

**SURFACE MOUNT GLASS PASSIVATED
FAST RECOVERY SILICON RECTIFIER**
VOLTAGE RANGE 50 to 1000 Volts CURRENT 3.0 Amperes

FEATURES

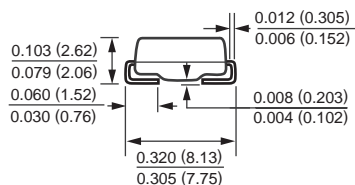
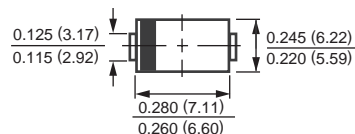
- * Glass passivated device
- * Ideal for surface mounted applications
- * Low leakage current
- * Metallurgically bonded construction
- * Mounting position: Any
- * Weight: 0.24 gram

MECHANICAL DATA

- * Epoxy : Device has UL flammability classification 94V-0



DO-214AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	FFM301	FFM302	FFM303	FFM304	FFM305	FFM306	FFM307	UNITS	
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts	
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts	
Maximum DC Blocking Voltage	Vdc	50	100	200	400	600	800	1000	Volts	
Maximum Average Forward Rectified Current at TA = 55°C	Io	3.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	200								Amps
Maximum Thermal Resistance	(Note 2) RθJL	15								°C/W
	(Note 3) RθJA	50								°C/W
Typical Junction Capacitance (Note 1)	CJ	60								pF
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 175								°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	FFM301	FFM302	FFM303	FFM304	FFM305	FFM306	FFM307	UNITS	
Maximum Forward Voltage at 3.0A DC	VF	1.3								Volts
Maximum Full Load Reverse Current, Full cycle Average at TA=55°C	IR	50								uAmps
Maximum DC Reverse Current at @TA = 25°C		10								uAmps
Rated DC Blocking Voltage @TA = 125°C		300								uAmps
Maximum Reverse Recovery Time (Note 4)	trr	150			250	500			nSec	

- NOTES : 1. Measured at 1.0 MHz and applied average voltage of 4.0VDC
 2. Thermal resistance junction to terminal 6.0mm² copper pads to each terminal.
 3. Thermal resistance junction to ambient, 6.0mm² copper pads to each terminal.
 4. Test Conditions: IF = 0.5A, IR = -1.0A, IRR = -0.25A

RATING AND CHARACTERISTIC CURVES (FFM301 THRU FFM307)

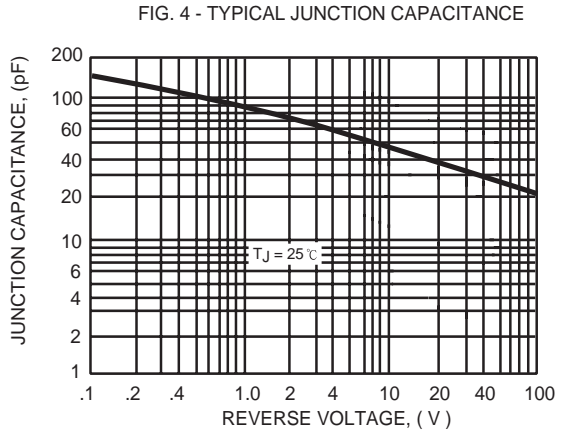
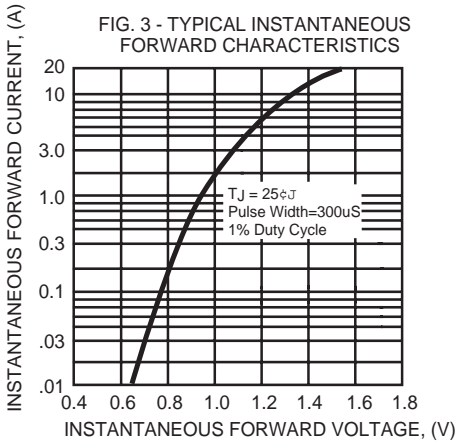
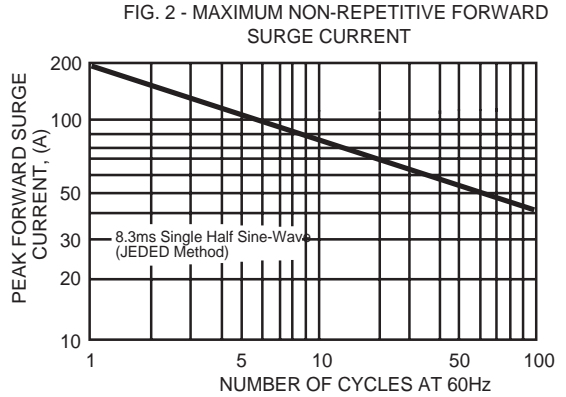
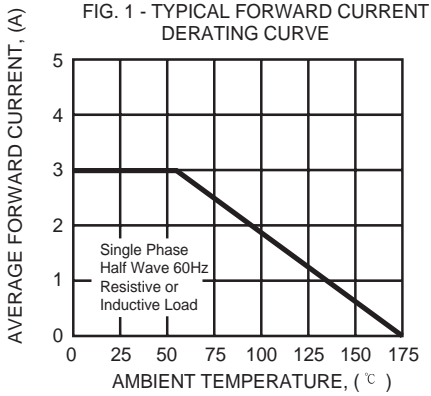
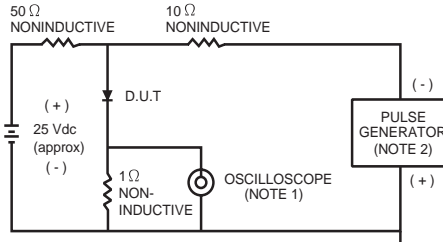


FIG. 5 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



- NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

